

**JX012N2 1.25A Sensitive SCR**

Rev.A.1.1

DESCRIPTION:

The JX012N2 SCR provides high dV/dt rate with strong resistance to electromagnetic interface. It is especially recommended for use on residual current circuit breaker, straight hair, igniter etc. Package SOT-89-2L is RoHS compliant.

MAIN FEATURES

Symbol	Value	Unit
$I_{T(RMS)}$	1.25	A
V_{DRM}/V_{RRM}	1200	V
I_{GT}	≤ 200	μA

ABSOLUTE MAXIMUM RATINGS

Parameter	Symbol	Value	Unit
Storage junction temperature range	T_{stg}	-40-150	
Operating junction temperature range	T_j	-40-110	
Repetitive peak off-state voltage ($T_j=25^\circ C$)	V_{DRM}	1200	V
Repetitive peak reverse voltage ($T_j=25^\circ C$)	V_{RRM}	1200	V
Average on-state current ($T_c \leq 49^\circ C$)	$I_{T(AV)}$	0.8	A
RMS on-state current ($T_c \leq 49^\circ C$)	$I_{T(RMS)}$	1.25	A
Non repetitive surge peak on-state current ($t_p=10ms$, $T_j=25^\circ C$)	I_{TSM}	20	A
Non repetitive surge peak on-state current ($t_p=8.3ms$, $T_j=25^\circ C$)		22	

ORDERING INFORMATION

<u>J</u>	<u>X</u>	<u>012</u>	<u>N2</u>
JieJie Microelectronics Co., Ltd.	Sensitive gate SCRs	Part number	N2:SOT-89-2L

MARKING

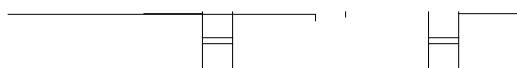
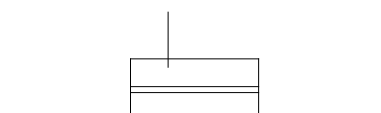


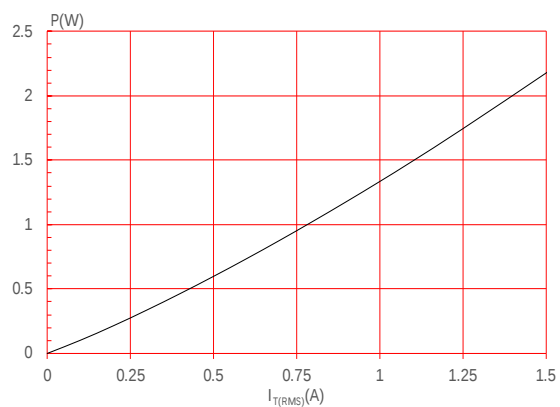
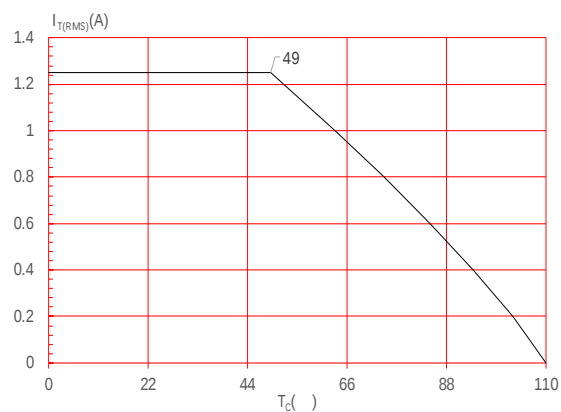
FIG.1: Maximum power dissipation versus RMS on-state current**FIG.3:** RMS on-state current versus ambient temperature (printed circuit board FR4,copper)**FIG.2:** RMS on-state current versus case temperature

FIG.7: Relative variations of gate trigger current,

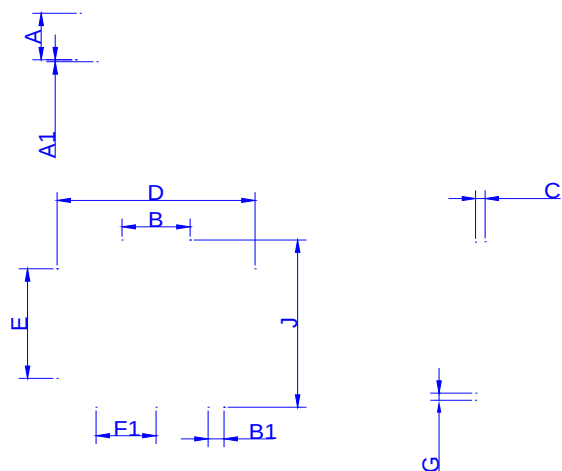
ORDERING INFORMATION

Order code	Voltage $V_{\text{DRM}}/V_{\text{RRM}}$ (V)	IGT(μA)	Package	Base qty. (pcs)	Delivery mode
JX012N2	1200	≤ 200	SOT-89-2L	4,000	Tape & Reel

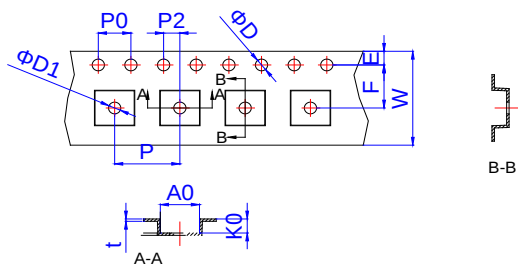
Document Revision History

Date	Revision	Changes
Apr.12, 2023	A.1.0	Last update
Oct.16, 2025	A.1.1	Revise PACKAGE MECHANICAL DATA

PACKAGE MECHANICAL DATA



DELIVERY MODE



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
E	1.65	1.75	1.85	0.065	0.069	0.073
F	5.45	5.50	5.55	0.215	0.217	0.219
P2	1.90	2.00	2.10	0.075	0.079	0.082
D	-	1.50	1.60	-	0.059	0.063
D1	1.50			0.059		
P0	3.90	4.00	4.10	0.154	0.157	0.161
10P0	39.80	40.00	40.20	1.567	1.575	1.583
W			12.30			0.482
P	7.90	8.00	8.10	0.311	0.315	0.319
A0	5.20	5.30	5.40	0.204	0.208	0.212
B0	4.80	4.90	5.00	0.188	0.192	0.196
K0	1.75	1.85	1.95	0.069	0.073	0.076
t	0.20	0.25	0.30	0.008	0.010	0.012
θ	3°		5°	3°		5°

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